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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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**Micro Commercial Components** 

Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939 MT60CB08T1 MT60CB12T1 MT60CB16T1 MT60CB18T1

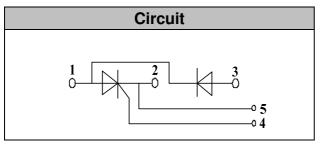
#### **Features**

- Lead Free Finish/RoHS Compliant (NOTE 1)("P" Suffix designates RoHS Compliant. See ordering information)
- International standard package
- Heat transfer through aluminum oxide DBC ceramic isolated metal baseplate
- Glass passivated chip
- Simple Mounting

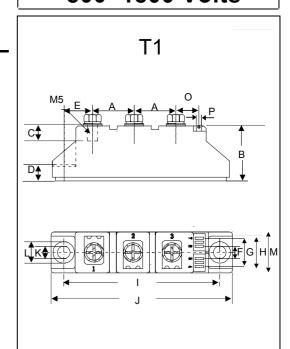
### **Applications**

- Power Converters
- · Lighting Control
- DC Motor Control and Drives
- · Heat and temperature control





# 60 Amp THYRISTOR/DIODE MODULE 800~1800 Volts



		DIME	NSIONS		
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.776	.799	19.70	20.30	
В	1.169	1.193	29.70	30.30	
С	.343	.366	8.70	9.30	
D	.323	.346	8.20	8.80	
Е	.602	.622	15.30	15.80	
F	.224	.248	5.70	6.30	
G	.539	.563	13.70	14.30	
Н	.657	.681	16.70	17.30	
_	3.138	3.161	79.70	80.30	
J	3.650	3.673	92.70	93.30	
K	.2	56	6.5	50	Ø
L	.421	.445	10.70	11.30	
М	.815	.839	20.70	21.30	
0	.579	.602	14.70	15.30	
Р	0.11	X0.032	2.8X	2.8X0.8	



**Module Type** 

TYPE	VRRM	Vrsm
MT60CB08T1	800V	900V
MT60CB12T1	1200V	1300V
MT60CB16T1	1600V	1700V
MT60CB18T1	1800V	1900V

#### **♦**Diode

**Maximum Ratings** 

Symbol	Item	Conditions	Values	Units
ΙD	Output Current(D.C.)	Tc=85℃	60	Α
IFSM	Surge forward current	t=10mS Tvj =45℃	1500	Α
i <sup>2</sup> t	Circuit Fusing Consideration		11000	A <sup>2</sup> s
Visol	Isolation Breakdown Voltage(R.M.S)	a.c.50HZ;r.m.s.;1min	3000	V
Tvj	Operating Junction Temperature		-40 to +125	$^{\circ}$ C
Tstg	Storage Temperature		-40 to +125	$^{\circ}$ C
Mt	Mounting Torque	To terminals(M5)	3±15%	Nm
Ms		To heatsink(M6)	5±15%	Nm
Weight	Module (Approximately)		100	g

#### **Thermal Characteristics**

Symbol	Item	Conditions	Values	Units
Rth(j-c)	Thermal Impedance, max.	Junction to Case	0.29	°C/W
Rth(c-s)	Thermal Impedance, max.	Case to Heatsink	0.10	°C/W

#### **Electrical Characteristics**

Symbol	Item	Conditions	Values			Units
Symbol	iteiii		Min.	Тур.	Max.	Uiilis
VFM	Forward Voltage Drop, max.	T=25°C IF =200A			1.65	V
IRRM	Repetitive Peak Reverse Current, max.	T <sub>vj</sub> =25°C VRD=VRRM T <sub>vj</sub> =125°C VRD=VRRM		≤0.5 ≤6		mA mA



# **♦**Thyristor Maximum Ratings

Symbol	Item	Conditions	Values	Units
I <sub>TAV</sub>	Average On-State Current	Sine 180°;Tc=85℃	60	Α
I <sub>TSM</sub>	Surge On-State Current	$T_{VJ}$ =45°C t=10ms, sine $T_{VJ}$ =125°C t=10ms, sine	1500 1250	Α
i <sup>2</sup> t	Circuit Fusing Consideration	$T_{VJ}$ =45°C t=10ms, sine $T_{VJ}$ =125°C t=10ms, sine	11000 8000	A2s
Visol	Isolation Breakdown Voltage(R.M.S)	a.c.50HZ;r.m.s.;1min	3000	V
Tvj	Operating Junction Temperature		-40 to +125	$^{\circ}\!\mathbb{C}$
Tstg	Storage Temperature		-40 to +125	$^{\circ}\mathbb{C}$
Mt	Mounting Torque	To terminals(M5)	$3\pm15\%$	Nm
Ms		To heatsink(M6)	5±15%	Nm
di/dt	Critical Rate of Rise of On-State Current	$T_{VJ}$ = $T_{VJM}$ , 2/3 $V_{DRM}$ , $I_{G}$ =500mA Tr<0.5us,tp>6us	150	A/us
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	T <sub>J</sub> =T <sub>VJM</sub> ,2/3V <sub>DRM</sub> linear voltage rise	1000	V/us
а	Maximum allowable acceleration		50	m/s <sup>2</sup>

#### **Thermal Characteristics**

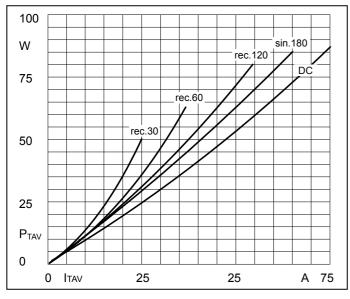
Symbol	Item	Conditions	Values	Units
Rth(j-c)	Thermal Impedance, max.	Junction to Case	0.57	<b>℃/W</b>
Rth(c-s)	Thermal Impedance, max.	Case to Heatsink	0.20	°C/W

#### **Electrical Characteristics**

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Symbol	Item	Conditions			Units
$V_{TM}$	Peak On-State Voltage, max.	T=25℃ I <sub>T</sub> =200A		1.65	V
I <sub>RRM</sub> /I <sub>DRM</sub>	Repetitive Peak Reverse Current, max. / Repetitive Peak Off-State Current, max.	$T_{VJ}=T_{VJM}$ , $V_R=V_{RRM}$ , $V_D=V_{DRM}$		15	mA
V <sub>TO</sub>	On state threshold voltage	For power-loss calculations only (T <sub>VJ</sub> =125℃)		0.9	V
r <sub>T</sub>	Value of on-state slope resistance. max	$T_{VJ} = T_{VJM}$		3.5	mΩ
$V_{GT}$	Gate Trigger Voltage, max.	T <sub>VJ</sub> =25℃ , V <sub>D</sub> =6V		3.0	V
I <sub>GT</sub>	Gate Trigger Current, max.	$T_{VJ}$ =25°C , $V_D$ =6V		150	mA
$V_{\sf GD}$	Non-triggering gate voltage, max.	$T_{VJ}$ =125°C, $V_D$ =2/3 $V_{DRM}$		0.25	V
$I_{GD}$	Non-triggering gate current, max.	$T_{VJ}$ =125°C, $V_D$ =2/3 $V_{DRM}$		6	mA
Ι <sub>L</sub>	Latching current, max.	$T_{VJ}$ =25°C , $R_G$ = 33 $\Omega$	300	600	mA
I <sub>H</sub>	Holding current, max.	T <sub>VJ</sub> =25℃ , V <sub>D</sub> =6V	150	250	mA
tgd	Gate controlled delay time	TVJ=25℃, IG=1A, diG/dt=1A/us	1		us
tq	Circuit commutated turn-off time	$T_{VJ} = T_{VJM}$	80		us



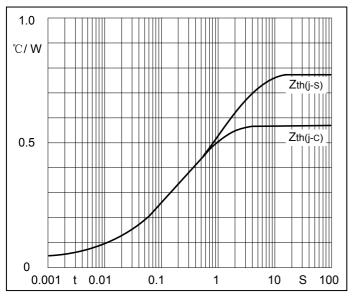
#### **Performance Curves**



90 Α = bc = 72 sin.180 rec.120 54 rec.60 36 rec.30 18  $I_{TAVM}$ 0 0 Tc 100 50 ℃ 130

Fig1. Power dissipation

**Fig2.Forward Current Derating Curve** 





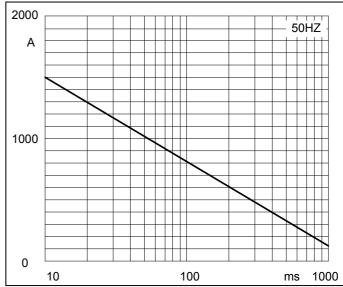


Fig4. Max Non-Repetitive Forward Surge Current



#### **Performance Curves**

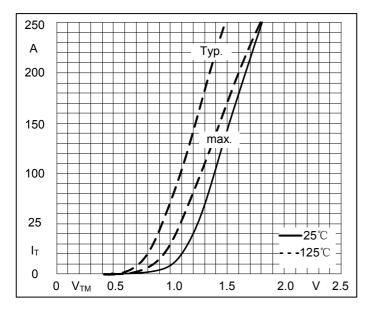


Fig5. Forward Characteristics

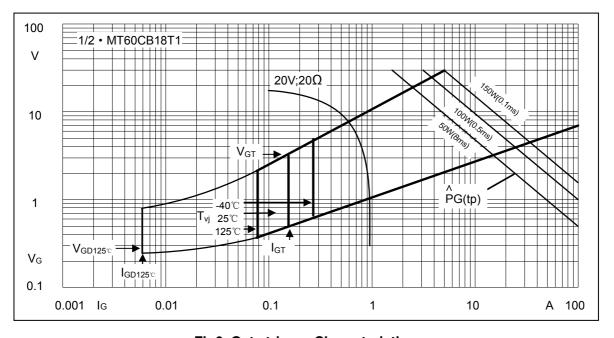


Fig6. Gate trigger Characteristics



#### **Ordering Information:**

Device	Packing
Part Number-BP	Bulk: 10PCS/BOX;100PCS/CTN

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